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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

|                                |                                                                                                                                                                   |
|--------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Product Status                 | Active                                                                                                                                                            |
| Number of LABs/CLBs            | -                                                                                                                                                                 |
| Number of Logic Elements/Cells | 27696                                                                                                                                                             |
| Total RAM Bits                 | 1130496                                                                                                                                                           |
| Number of I/O                  | 138                                                                                                                                                               |
| Number of Gates                | -                                                                                                                                                                 |
| Voltage - Supply               | 1.14V ~ 2.625V                                                                                                                                                    |
| Mounting Type                  | Surface Mount                                                                                                                                                     |
| Operating Temperature          | 0°C ~ 85°C (TJ)                                                                                                                                                   |
| Package / Case                 | 256-LFBGA                                                                                                                                                         |
| Supplier Device Package        | 256-FPBGA (14x14)                                                                                                                                                 |
| Purchase URL                   | <a href="https://www.e-xfl.com/product-detail/microchip-technology/m2gl025ts-vf256">https://www.e-xfl.com/product-detail/microchip-technology/m2gl025ts-vf256</a> |

## 1.9 Revision 3.0

In revision 3.0 of this document, the Theta B/C columns and FCS325 package was updated. For more information, see Table 9, page 10 (SAR 62002).

## 1.10 Revision 2.0

The following is a summary of the changes in revision 2.0 of this document.

- Table 1, page 4 was updated (SAR 59056).
- Table 7, page 8 temperature and data retention information was updated SAR (61363).
- Storage Operating Table was updated and split into three tables – Table 5, page 7, Table 7, page 8 (SAR 58725).
- Updated Theta B/C columns and FCS325 package in Table 9, page 10 (SAR 62002).
- Added 090-FCS325 thermal resistance to Table 9, page 10 (SAR 59384).
- TQ144 package was added to Table 9, page 10 (SAR 57708).
- Added PLL jitter data for the VF400 package (SAR 53162).
- Added Additional Worst Case IDD to Table 11, page 12 and Table 12, page 13 (SAR 59077).
- Table 13, page 13, Table 14, page 13, and Table 15, page 14 were added to verify Inrush currents (SAR 56348).
- Table 18, page 19 and Table 21, page 20 – I/O speeds were replaced.
- Max speed was changed in Table 41, page 26 (SAR 57221) and in Table 52, page 29 (SAR 57113).
- Minimum and Maximum DC/AC Input and Output Levels Specification, page 29 and Table 49, page 29–Table 57, page 31 were added.
- Added Cload to Table 89, page 39 (SAR 56238).
- Removed "Rs" information in DDR Timing Measurement Table 123, page 47, Table 133, page 49, and Table 144, page 52.
- Updated drive programming for M/B-LVDS outputs (SAR 58154).
- Added an inverter bubble to DDR\_IN latch in Figure 10, page 70 (SAR 61418).
- QF waveform in Figure 11, page 71 was updated (SAR 59816).
- uSRAM Write Clock minimum values were updated in Table 237, page 86–Table 243, page 93 (SAR 55236).
- Fixed typo in the 32 kHz Crystal (XTAL) oscillator accuracy data section (SAR 59669).
- The "On-Chip Oscillator" section was split, and the Embedded NVM (eNVM) Characteristics, page 104 was added. Table 277, page 107–Table 281, page 109 were revised.(SARs 57898 and 59669).
- PLL VCP Frequency and conditions were added to Table 282, page 110 (SAR 57416).
- Fixed typo for PLL jitter data in the 100-400 MHz range (SAR 60727).
- Updated FCCC information in Table 282, page 110 and Table 283, page 111 (SAR 60799).
- Device 025 specifications were added to Table 283, page 111 (SAR 51625).
- JTAG Table 284, page 112 was replaced (SAR 51188).
- Flash\*Freeze Table 293, page 119 was replaced (SAR 57828).
- Added support for HCSL I/O Standard for SERDES reference clocks in Table 300, page 123 and Table 301, page 123 (SAR 50748).
- Tir and Tif parameters were added to Table 303, page 124 (SAR 52203).
- Speed grade consistency was fixed in tables throughout the datasheet (SAR 50722).
- Added jitter attenuation information (SAR 59405).

## 1.11 Revision 1.0

The following is a summary of the changes in revision 1.0 of this document.

- The IGLOO2 v2 and the SmartFusion2 v5 datasheets are combined into this single product family datasheet.

**Figure 1 • High Temperature Data Retention (HTR)****2.3.1.1 Overshoot/Undershoot Limits**

For AC signals, the input signal may undershoot during transitions to  $-1.0$  V for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

For AC signals, the input signal may overshoot during transitions to  $V_{CCI} + 1.0$  V for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

**Note:** The above specifications do not apply to the PCI standard. The IGLOO2 and SmartFusion2 PCI I/Os are compliant with the PCI standard including the PCI overshoot/undershoot specifications.

**2.3.1.2 Thermal Characteristics**

The temperature variable in the Microsemi SoC Products Group Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption causes the chip's junction temperature to be higher than the ambient, case, or board temperatures.

EQ1 through EQ3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - T_A}{P}$$

EQ 1

$$\theta_{JB} = \frac{T_J - T_B}{P}$$

EQ 2

$$\theta_{JC} = \frac{T_J - T_C}{P}$$

EQ 3

## 2.3.4 Timing Model

This section describes timing model and timing parameters.

**Figure 2 • Timing Model**

The following table lists the timing model parameters in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 17 • Timing Model Parameters**

| Index | Symbol      | Description                                 | –1    | Unit | For More Information   |
|-------|-------------|---------------------------------------------|-------|------|------------------------|
| A     | $T_{PY}$    | Propagation delay of DDR3 receiver          | 1.605 | ns   | See Table 137, page 50 |
| B     | $T_{ICLKQ}$ | Clock-to-Q of the input data register       | 0.16  | ns   | See Table 221, page 71 |
|       | $T_{ISUD}$  | Setup time of the input data register       | 0.357 | ns   | See Table 221, page 71 |
| C     | $T_{RCKH}$  | Input high delay for global clock           | 1.53  | ns   | See Table 227, page 78 |
|       | $T_{RCKL}$  | Input low delay for global clock            | 0.897 | ns   | See Table 227, page 78 |
| D     | $T_{PY}$    | Input propagation delay of LVDS receiver    | 2.774 | ns   | See Table 167, page 56 |
| E     | $T_{DP}$    | Propagation delay of a three-input AND gate | 0.198 | ns   | See Table 223, page 76 |

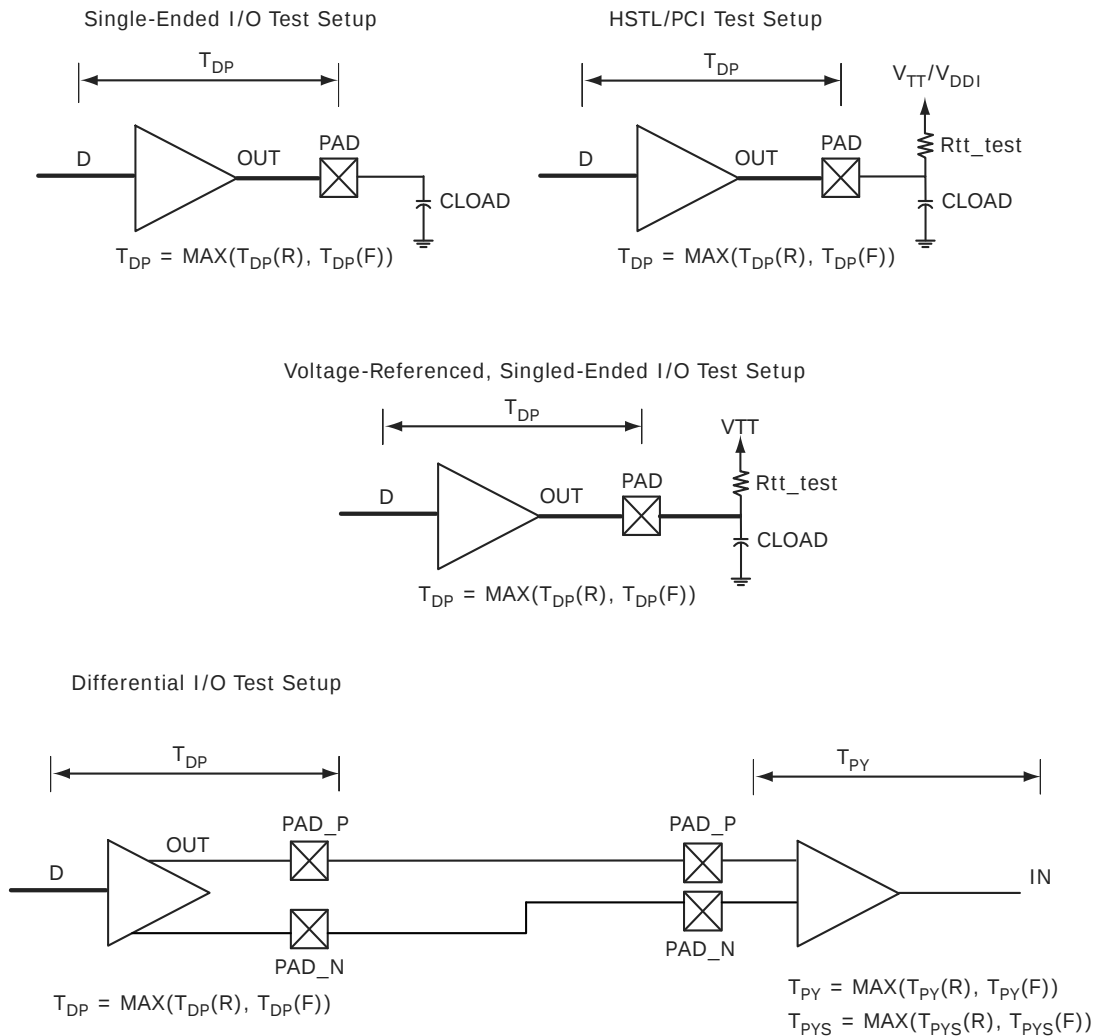
**Table 17 • Timing Model Parameters (continued)**

| Index | Symbol      | Description                                                                                         | –1    | Unit | For More Information   |
|-------|-------------|-----------------------------------------------------------------------------------------------------|-------|------|------------------------|
| F     | $T_{DP}$    | Propagation delay of an OR gate                                                                     | 0.179 | ns   | See Table 223, page 76 |
| G     | $T_{DP}$    | Propagation delay of an LVDS transmitter                                                            | 2.136 | ns   | See Table 169, page 57 |
| H     | $T_{DP}$    | Propagation delay of a three-input XOR Gate                                                         | 0.241 | ns   | See Table 223, page 76 |
| I     | $T_{DP}$    | Propagation delay of LVCMOS 2.5 V transmitter, drive strength of 16 mA on the MSIO bank             | 2.412 | ns   | See Table 46, page 27  |
| J     | $T_{DP}$    | Propagation delay of a two-input NAND gate                                                          | 0.179 | ns   | See Table 223, page 76 |
| K     | $T_{DP}$    | Propagation delay of LVCMOS 2.5 V transmitter, drive strength of 8 mA on the MSIO bank              | 2.309 | ns   | See Table 46, page 27  |
| L     | $T_{CLKQ}$  | Clock-to-Q of the data register                                                                     | 0.108 | ns   | See Table 224, page 77 |
|       | $T_{SUD}$   | Setup time of the data register                                                                     | 0.254 | ns   | See Table 224, page 77 |
| M     | $T_{DP}$    | Propagation delay of a two-input AND gate                                                           | 0.179 | ns   | See Table 223, page 76 |
| N     | $T_{OCLKQ}$ | Clock-to-Q of the output data register                                                              | 0.263 | ns   | See Table 220, page 69 |
|       | $T_{OSUD}$  | Setup time of the output data register                                                              | 0.19  | ns   | See Table 220, page 69 |
| O     | $T_{DP}$    | Propagation delay of SSTL2, Class I transmitter on the MSIO bank                                    | 2.055 | ns   | See Table 114, page 45 |
| P     | $T_{DP}$    | Propagation delay of LVCMOS 1.5 V transmitter, drive strength of 12 mA, fast slew on the DDRIO bank | 3.316 | ns   | See Table 70, page 34  |

### 2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

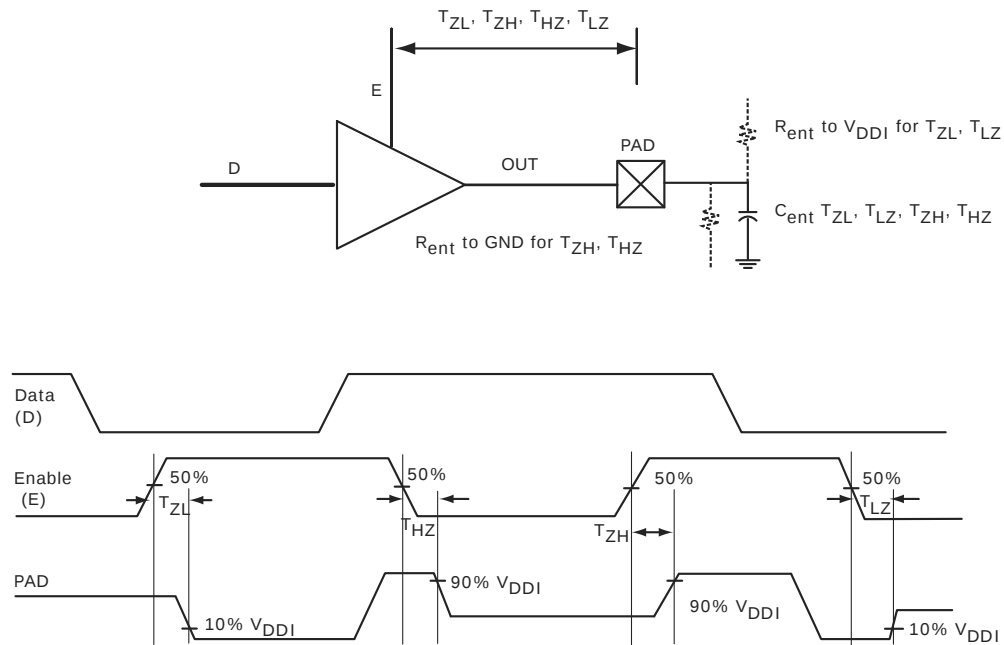
**Figure 4 • Output Buffer AC Loading**



### 2.3.5.3 Tristate Buffer and AC Loading

The tristate path for enable path loadings is described in the respective specifications. The following figure shows the methodology of characterization illustrated by the enable path test point.

**Figure 5 • Tristate Buffer for Enable Path Test Point**



### 2.3.5.4 I/O Speeds

This section describes the maximum data rate summary of I/O in worst-case industrial conditions. See the individual I/O standards for operating conditions.

**Table 18 • Maximum Data Rate Summary Table for Single-Ended I/O in Worst-Case Industrial Conditions**

| I/O                      | MSIO | MSIOD | DDRIO | Unit |
|--------------------------|------|-------|-------|------|
| PCI 3.3 V                | 630  |       |       | Mbps |
| LVTTL 3.3 V              | 600  |       |       | Mbps |
| LVC MOS 3.3 V            | 600  |       |       | Mbps |
| LVC MOS 2.5 V            | 410  | 420   | 400   | Mbps |
| LVC MOS 1.8 V            | 295  | 400   | 400   | Mbps |
| LVC MOS 1.5 V            | 160  | 220   | 235   | Mbps |
| LVC MOS 1.2 V            | 120  | 160   | 200   | Mbps |
| LPDDR-LVC MOS 1.8 V mode |      |       | 400   | Mbps |

## 2.3.5.6 Single-Ended I/O Standards

### 2.3.5.6.1 Low Voltage Complementary Metal Oxide Semiconductor (LVCMOS)

LVCMOS is a widely used switching standard implemented in CMOS transistors. This standard is defined by JEDEC (JESD 8-5). The LVCMOS standards supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs are: LVCMOS12, LVCMOS15, LVCMOS18, LVCMOS25, and LVCMOS33.

### 2.3.5.6.2 3.3 V LVCMOS/LVTTL

LVCMOS 3.3 V or Low-Voltage Transistor-Transistor Logic (LVTTL) is a general standard for 3.3 V applications.

#### Minimum and Maximum DC/AC Input and Output Levels Specification

**Table 29 • LVTTL/LVCMOS 3.3 V DC Recommended DC Operating Conditions (Applicable to MSIO I/O Bank Only)**

| Parameter      | Symbol    | Min  | Typ | Max  | Unit |
|----------------|-----------|------|-----|------|------|
| Supply voltage | $V_{DDI}$ | 3.15 | 3.3 | 3.45 | V    |

**Table 30 • LVTTL/LVCMOS 3.3 V Input Voltage Specification (Applicable to MSIO I/O Bank Only)**

| Parameter                       | Symbol        | Min  | Max  | Unit |
|---------------------------------|---------------|------|------|------|
| DC input logic high             | $V_{IH}$ (DC) | 2.0  | 3.45 | V    |
| DC input logic low              | $V_{IL}$ (DC) | −0.3 | 0.8  | V    |
| Input current high <sup>1</sup> | $I_{IH}$ (DC) |      |      |      |
| Input current low <sup>1</sup>  | $I_{IL}$ (DC) |      |      |      |

1. See Table 24, page 22.

**Table 31 • LVCMOS 3.3 V DC Output Voltage Specification (Applicable to MSIO I/O Bank Only)**

| Parameter                         | Symbol   | Min             | Max | Unit |
|-----------------------------------|----------|-----------------|-----|------|
| DC output logic high <sup>1</sup> | $V_{OH}$ | $V_{DDI} - 0.4$ |     | V    |
| DC output logic low <sup>1</sup>  | $V_{OL}$ |                 | 0.4 | V    |

1. The  $V_{OH}/V_{OL}$  test points selected ensure compliance with LVCMOS 3.3 V JESD8-B requirements.

**Table 32 • LVTTL 3.3 V DC Output Voltage Specification (Applicable to MSIO I/O Bank Only)**

| Parameter            | Symbol   | Min | Max | Unit |
|----------------------|----------|-----|-----|------|
| DC output logic high | $V_{OH}$ | 2.4 |     | V    |
| DC output logic low  | $V_{OL}$ |     | 0.4 | V    |

**Table 33 • LVTTL/LVCMOS 3.3 V AC Maximum Switching Speed (Applicable to MSIO I/O Bank Only)**

| Parameter                             | Symbol    | Max | Unit | Conditions                                 |
|---------------------------------------|-----------|-----|------|--------------------------------------------|
| Maximum data rate (for MSIO I/O bank) | $D_{MAX}$ | 600 | Mbps | AC loading: 17 pF load, maximum drive/slew |

**Table 43 • LVCMOS 2.5 V AC Test Parameter Specifications**

| Parameter                                                                        | Symbol     | Typ | Unit           |
|----------------------------------------------------------------------------------|------------|-----|----------------|
| Measuring/trip point for data path                                               | $V_{TRIP}$ | 1.2 | V              |
| Resistance for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )         | $R_{ENT}$  | 2K  | $\Omega\sigma$ |
| Capacitive loading for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ ) | $C_{ENT}$  | 5   | pF             |
| Capacitive loading for data path ( $T_{DP}$ )                                    | $C_{LOAD}$ | 5   | pF             |

**Table 44 • LVCMOS 2.5 V Transmitter Drive Strength Specifications**

| Output Drive Selection |                |                                                         | VOH (V)         | VOL (V) | IOH (at VOH) mA | IOL (at VOL) mA |
|------------------------|----------------|---------------------------------------------------------|-----------------|---------|-----------------|-----------------|
| MSIO I/O Bank          | MSIOD I/O Bank | DDRIO I/O Bank<br>(With Software Default<br>Fixed Code) | Min             | Max     |                 |                 |
| 2 mA                   | 2 mA           | 2 mA                                                    | $V_{DDI} - 0.4$ | 0.4     | 2               | 2               |
| 4 mA                   | 4 mA           | 4 mA                                                    | $V_{DDI} - 0.4$ | 0.4     | 4               | 4               |
| 6 mA                   | 6 mA           | 6 mA                                                    | $V_{DDI} - 0.4$ | 0.4     | 6               | 6               |
| 8 mA                   | 8 mA           | 8 mA                                                    | $V_{DDI} - 0.4$ | 0.4     | 8               | 8               |
| 12 mA                  | 12 mA          | 12 mA                                                   | $V_{DDI} - 0.4$ | 0.4     | 12              | 12              |
| 16 mA                  |                | 16 mA                                                   | $V_{DDI} - 0.4$ | 0.4     | 16              | 16              |

**Note:** For board design considerations, output slew rates extraction, detailed output buffer resistances, and I/V Curve, use the corresponding IBIS models located at:  
[www.microsemi.com/soc/download/ibis/default.aspx](http://www.microsemi.com/soc/download/ibis/default.aspx).

#### AC Switching Characteristics

Worst commercial-case conditions:  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 2.375\text{ V}$

**Table 45 • LVCMOS 2.5 V Receiver Characteristics (Input Buffers)**

|                                   | On-Die Termination<br>(ODT) | $T_{PY}$ |       | $T_{PYS}$ |       | Unit |
|-----------------------------------|-----------------------------|----------|-------|-----------|-------|------|
|                                   |                             | -1       | -Std  | -1        | -Std  |      |
| LVCMOS 2.5 V (for DDRIO I/O bank) | None                        | 1.823    | 2.145 | 1.932     | 2.274 | ns   |
| LVCMOS 2.5 V (for MSIO I/O bank)  | None                        | 2.486    | 2.925 | 2.495     | 2.935 | ns   |
| LVCMOS 2.5 V (for MSIOD I/O bank) | None                        | 2.29     | 2.694 | 2.305     | 2.712 | ns   |

**Table 46 • LVCMOS 2.5 V Transmitter Characteristics for DDRIO Bank (Output and Tristate Buffers)**

| Output<br>Drive<br>Selection | Slew<br>Control | $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}^1$ |       | $T_{LZ}^1$ |       | Unit |
|------------------------------|-----------------|----------|-------|----------|-------|----------|-------|------------|-------|------------|-------|------|
|                              |                 | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1         | -Std  | -1         | -Std  |      |
| 2 mA                         | Slow            | 3.657    | 4.302 | 3.393    | 3.991 | 3.675    | 4.323 | 3.894      | 4.582 | 3.552      | 4.18  | ns   |
|                              | Medium          | 3.374    | 3.97  | 3.139    | 3.693 | 3.396    | 3.995 | 3.635      | 4.277 | 3.253      | 3.828 | ns   |
|                              | Medium fast     | 3.239    | 3.811 | 3.036    | 3.572 | 3.261    | 3.836 | 3.519      | 4.141 | 3.128      | 3.681 | ns   |
|                              | Fast            | 3.224    | 3.793 | 3.029    | 3.563 | 3.246    | 3.818 | 3.512      | 4.132 | 3.119      | 3.67  | ns   |

**Table 48 • LVCMOS 2.5 V Transmitter Characteristics for MSIOD Bank (Output and Tristate Buffers)**

| Output Drive Selection | Slew Control | $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}^1$ |       | $T_{LZ}^1$ |       | Unit |
|------------------------|--------------|----------|-------|----------|-------|----------|-------|------------|-------|------------|-------|------|
|                        |              | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1         | -Std  | -1         | -Std  |      |
| 2 mA                   | Slow         | 2.206    | 2.596 | 2.678    | 3.15  | 2.64     | 3.106 | 4.935      | 5.805 | 4.74       | 5.576 | ns   |
| 4 mA                   | Slow         | 1.835    | 2.159 | 2.242    | 2.637 | 2.256    | 2.654 | 5.413      | 6.368 | 5.15       | 6.059 | ns   |
| 6 mA                   | Slow         | 1.709    | 2.01  | 2.132    | 2.508 | 2.167    | 2.549 | 5.813      | 6.838 | 5.499      | 6.469 | ns   |
| 8 mA                   | Slow         | 1.63     | 1.918 | 1.958    | 2.303 | 2.012    | 2.367 | 6.226      | 7.324 | 5.816      | 6.842 | ns   |
| 12 mA                  | Slow         | 1.648    | 1.939 | 1.86     | 2.187 | 1.921    | 2.259 | 6.519      | 7.669 | 6.027      | 7.09  | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

### 2.3.5.8 1.8 V LVCMOS

LVCMOS 1.8 is a general standard for 1.8 V applications and is supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs in compliance to the JEDEC specification JESD8-7A.

#### Minimum and Maximum DC/AC Input and Output Levels Specification

**Table 49 • LVCMOS 1.8 V DC Recommended Operating Conditions**

| Parameter                                               | Symbol    | Min   | Typ | Max  | Unit |
|---------------------------------------------------------|-----------|-------|-----|------|------|
| <b>LVCMOS 1.8 V DC Recommended Operating Conditions</b> |           |       |     |      |      |
| Supply voltage                                          | $V_{DDI}$ | 1.710 | 1.8 | 1.89 | V    |

**Table 50 • LVCMOS 1.8 V DC Input Voltage Specification**

| Parameter                                           | Symbol        | Min                   | Max                   | Unit |
|-----------------------------------------------------|---------------|-----------------------|-----------------------|------|
| DC input logic high (for MSIOD and DDRIO I/O banks) | $V_{IH}$ (DC) | $0.65 \times V_{DDI}$ | 1.89                  | V    |
| DC input logic high (for MSIO I/O bank)             | $V_{IH}$ (DC) | $0.65 \times V_{DDI}$ | 3.45                  | V    |
| DC input logic low                                  | $V_{IL}$ (DC) | -0.3                  | $0.35 \times V_{DDI}$ | V    |
| Input current high <sup>1</sup>                     | $I_{IH}$ (DC) |                       |                       | –    |
| Input current low <sup>1</sup>                      | $I_{IL}$ (DC) |                       |                       | –    |

1. See Table 24, page 22.

**Table 51 • LVCMOS 1.8 V DC Output Voltage Specification**

| Parameter            | Symbol   | Min              | Max  | Unit |
|----------------------|----------|------------------|------|------|
| DC output logic high | $V_{OH}$ | $V_{DDI} - 0.45$ |      | V    |
| DC output logic low  | $V_{OL}$ |                  | 0.45 | V    |

**Table 52 • LVCMOS 1.8 V Minimum and Maximum AC Switching Speed**

| Parameter                                           | Symbol    | Max | Unit | Conditions                                 |
|-----------------------------------------------------|-----------|-----|------|--------------------------------------------|
| Maximum data rate (for DDRIO I/O bank) <sup>1</sup> | $D_{MAX}$ | 400 | Mbps | AC loading: 17 pF load, maximum drive/slew |
| Maximum data rate (for MSIO I/O bank)               | $D_{MAX}$ | 295 | Mbps | AC loading: 17 pF load, maximum drive/slew |
| Maximum data rate (for MSIOD I/O bank) <sup>1</sup> | $D_{MAX}$ | 400 | Mbps | AC loading: 17 pF load, maximum drive/slew |

1. Maximum Data Rate applies for Drive Strength 8 mA and above, All Slews.

**Table 70 • LVCMOS 1.5 V Transmitter Characteristics for DDRIO I/O Bank (Output and Tristate Buffers)**  
(continued)

| Output Drive Selection | Slew Control | T <sub>DP</sub> |       | T <sub>ZL</sub> |       | T <sub>ZH</sub> |       | T <sub>HZ</sub> <sup>1</sup> |       | T <sub>LZ</sub> <sup>1</sup> |       | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
|                        |              | -1              | -Std  | -1              | -Std  | -1              | -Std  | -1                           | -Std  | -1                           | -Std  |      |
| 6 mA                   | Slow         | 4.244           | 4.993 | 3.465           | 4.076 | 4.233           | 4.979 | 6.39                         | 7.518 | 5.736                        | 6.748 | ns   |
|                        | Medium       | 3.774           | 4.44  | 3.05            | 3.587 | 3.762           | 4.426 | 6.114                        | 7.193 | 5.397                        | 6.35  | ns   |
|                        | Medium fast  | 3.544           | 4.17  | 2.839           | 3.339 | 3.529           | 4.152 | 5.978                        | 7.033 | 5.27                         | 6.2   | ns   |
|                        | Fast         | 3.519           | 4.14  | 2.82            | 3.317 | 3.504           | 4.122 | 5.965                        | 7.017 | 5.259                        | 6.187 | ns   |
| 8 mA                   | Slow         | 4.099           | 4.823 | 3.311           | 3.894 | 4.087           | 4.807 | 6.584                        | 7.746 | 5.854                        | 6.888 | ns   |
|                        | Medium       | 3.656           | 4.301 | 2.927           | 3.443 | 3.642           | 4.284 | 6.311                        | 7.425 | 5.553                        | 6.533 | ns   |
|                        | Medium fast  | 3.437           | 4.044 | 2.731           | 3.213 | 3.42            | 4.023 | 6.182                        | 7.273 | 5.435                        | 6.394 | ns   |
|                        | Fast         | 3.41            | 4.012 | 2.715           | 3.193 | 3.393           | 3.991 | 6.178                        | 7.269 | 5.425                        | 6.383 | ns   |
| 10 mA                  | Slow         | 4.029           | 4.74  | 3.238           | 3.809 | 4.015           | 4.723 | 6.732                        | 7.921 | 5.965                        | 7.018 | ns   |
|                        | Medium       | 3.601           | 4.237 | 2.867           | 3.372 | 3.586           | 4.218 | 6.473                        | 7.615 | 5.669                        | 6.669 | ns   |
|                        | Medium fast  | 3.384           | 3.981 | 2.672           | 3.143 | 3.365           | 3.958 | 6.351                        | 7.471 | 5.55                         | 6.529 | ns   |
|                        | Fast         | 3.357           | 3.949 | 2.655           | 3.123 | 3.338           | 3.927 | 6.345                        | 7.464 | 5.54                         | 6.518 | ns   |
| 12 mA                  | Slow         | 3.974           | 4.675 | 3.196           | 3.759 | 3.958           | 4.656 | 6.842                        | 8.049 | 6.068                        | 7.139 | ns   |
|                        | Medium       | 3.55            | 4.176 | 2.827           | 3.326 | 3.534           | 4.157 | 6.584                        | 7.746 | 5.751                        | 6.766 | ns   |
|                        | Medium fast  | 3.345           | 3.935 | 2.638           | 3.103 | 3.325           | 3.911 | 6.488                        | 7.633 | 5.641                        | 6.637 | ns   |
|                        | Fast         | 3.316           | 3.902 | 2.621           | 3.083 | 3.297           | 3.878 | 6.486                        | 7.63  | 5.626                        | 6.619 | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 71 • LVCMOS 1.5 V Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)**

| Output Drive Selection | Slew Control | T <sub>DP</sub> |       | T <sub>ZL</sub> |       | T <sub>ZH</sub> |       | T <sub>HZ</sub> <sup>1</sup> |       | T <sub>LZ</sub> <sup>1</sup> |       | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
|                        |              | -1              | -Std  | -1              | -Std  | -1              | -Std  | -1                           | -Std  | -1                           | -Std  |      |
| 2 mA                   | Slow         | 4.423           | 5.203 | 5.397           | 6.35  | 5.686           | 6.69  | 5.609                        | 6.599 | 5.561                        | 6.542 | ns   |
| 4 mA                   | Slow         | 4.05            | 4.765 | 4.503           | 5.298 | 4.92            | 5.788 | 7.358                        | 8.657 | 6.525                        | 7.677 | ns   |
| 6 mA                   | Slow         | 4.081           | 4.801 | 4.259           | 5.012 | 4.699           | 5.528 | 7.659                        | 9.011 | 6.709                        | 7.893 | ns   |
| 8 mA                   | Slow         | 4.234           | 4.98  | 4.068           | 4.786 | 4.521           | 5.319 | 8.218                        | 9.668 | 7.05                         | 8.294 | ns   |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 131 • SSTL15 DC Output Voltage Specification (for DDRIO I/O Bank Only)**

| Parameter                                       | Symbol               | Min                  | Max                  | Unit |
|-------------------------------------------------|----------------------|----------------------|----------------------|------|
| <b>DDR3/SSTL15 Class I (DDR3 Reduced Drive)</b> |                      |                      |                      |      |
| DC output logic high                            | $V_{OH}$             | $0.8 \times V_{DDI}$ |                      | V    |
| DC output logic low                             | $V_{OL}$             |                      | $0.2 \times V_{DDI}$ | V    |
| Output minimum source DC current                | $I_{OH}$ at $V_{OH}$ | 6.5                  |                      | mA   |
| Output minimum sink current                     | $I_{OL}$ at $V_{OL}$ | -6.5                 |                      | mA   |
| <b>DDR3/SSTL15 Class II (DDR3 Full Drive)</b>   |                      |                      |                      |      |
| DC output logic high                            | $V_{OH}$             | $0.8 \times V_{DDI}$ |                      | V    |
| DC output logic low                             | $V_{OL}$             |                      | $0.2 \times V_{DDI}$ | V    |
| Output minimum source DC current                | $I_{OH}$ at $V_{OH}$ | 7.6                  |                      | mA   |
| Output minimum sink current                     | $I_{OL}$ at $V_{OL}$ | -7.6                 |                      | mA   |

**Table 132 • SSTL15 DC Differential Voltage Specification (for DDRIO I/O Bank Only)**

| Parameter                     | Symbol   | Min | Unit |
|-------------------------------|----------|-----|------|
| DC input differential voltage | $V_{ID}$ | 0.2 | V    |

**Note:** To meet JEDEC electrical compliance, use DDR3 full drive transmitter.

**Table 133 • SSTL15 AC SSTL15 Minimum and Maximum AC Switching Speed (for DDRIO I/O Bank Only)**

| Parameter                           | Symbol          | Min                          | Max                          | Unit |
|-------------------------------------|-----------------|------------------------------|------------------------------|------|
| AC input differential voltage       | $V_{DIFF}$ (AC) | 0.3                          |                              | V    |
| AC differential cross point voltage | $V_x$ (AC)      | $0.5 \times V_{DDI} - 0.150$ | $0.5 \times V_{DDI} + 0.150$ | V    |

**Table 134 • SSTL15 Minimum and Maximum AC Switching Speed (for DDRIO I/O Bank Only)**

| Parameter         | Symbol    | Max | Unit | Conditions                           |
|-------------------|-----------|-----|------|--------------------------------------|
| Maximum data rate | $D_{MAX}$ | 667 | Mbps | AC loading: per JEDEC specifications |

**Table 135 • SSTL15 AC Calibrated Impedance Option (for DDRIO I/O Bank Only)**

| Parameter                                    | Symbol    | Typ                 | Unit     | Conditions                        |
|----------------------------------------------|-----------|---------------------|----------|-----------------------------------|
| Supported output driver calibrated impedance | $R_{REF}$ | 34, 40              | $\Omega$ | Reference resistor = 240 $\Omega$ |
| Effective impedance value (ODT)              | $R_{TT}$  | 20, 30, 40, 60, 120 | $\Omega$ | Reference resistor = 240 $\Omega$ |

### 2.3.6.6 Low Power Double Data Rate (LPDDR)

LPDDR reduced and full drive low power double data rate standards are supported in IGLOO2 FPGA and SmartFusion2 SoC FPGA I/Os. This standard requires a differential amplifier input buffer and a push-pull output buffer.

#### Minimum and Maximum DC/AC Input and Output Levels Specification

**Table 139 • LPDDR DC Recommended DC Operating Conditions**

| Parameter               | Symbol    | Min   | Typ   | Max   |
|-------------------------|-----------|-------|-------|-------|
| Supply voltage          | $V_{DDI}$ | 1.71  | 1.8   | 1.89  |
| Termination voltage     | $V_{TT}$  | 0.838 | 0.900 | 0.964 |
| Input reference voltage | $V_{REF}$ | 0.838 | 0.900 | 0.964 |

**Table 140 • LPDDR DC Input Voltage Specification**

| Parameter                       | Symbol        | Min                  | Max                  |
|---------------------------------|---------------|----------------------|----------------------|
| DC input logic high             | $V_{IH}$ (DC) | $0.7 \times V_{DDI}$ | 1.89                 |
| DC input logic low              | $V_{IL}$ (DC) | -0.3                 | $0.3 \times V_{DDI}$ |
| Input current high <sup>1</sup> | $I_{IH}$ (DC) |                      |                      |
| Input current low <sup>1</sup>  | $I_{IL}$ (DC) |                      |                      |

1. See Table 24, page 22.

**Table 141 • LPDDR DC Output Voltage Specification Reduced Drive**

| Parameter                        | Symbol               | Min                  | Max                  |
|----------------------------------|----------------------|----------------------|----------------------|
| DC output logic high             | $V_{OH}$             | $0.9 \times V_{DDI}$ |                      |
| DC output logic low              | $V_{OL}$             |                      | $0.1 \times V_{DDI}$ |
| Output minimum source DC current | $I_{OH}$ at $V_{OH}$ | 0.1                  |                      |
| Output minimum sink current      | $I_{OL}$ at $V_{OL}$ | -0.1                 |                      |

**Table 142 • LPDDR DC Output Voltage Specification Full Drive<sup>1</sup>**

| Parameter                        | Symbol               | Min                  | Max                  |
|----------------------------------|----------------------|----------------------|----------------------|
| DC output logic high             | $V_{OH}$             | $0.9 \times V_{DDI}$ |                      |
| DC output logic low              | $V_{OL}$             |                      | $0.1 \times V_{DDI}$ |
| Output minimum source DC current | $I_{OH}$ at $V_{OH}$ | 0.1                  |                      |
| Output minimum sink current      | $I_{OL}$ at $V_{OL}$ | -0.1                 |                      |

1. To meet JEDEC Electrical Compliance, use LPDDR Full Drive Transmitter.

**Table 143 • LPDDR DC Differential Voltage Specification**

| Parameter                     | Symbol        | Min                  |
|-------------------------------|---------------|----------------------|
| DC input differential voltage | $V_{ID}$ (DC) | $0.4 \times V_{DDI}$ |

**Table 159 • LPDDR-LVCMOS 1.8 V AC Switching Characteristics for Transmitter for DDRIO I/O Bank (Output and Tristate Buffers) (continued)**

|       |             |       |       |       |       |       |       |       |       |       |       |    |
|-------|-------------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|----|
| 10 mA | medium      | 3.246 | 3.819 | 2.686 | 3.16  | 3.236 | 3.807 | 5.542 | 6.52  | 4.936 | 5.807 | ns |
|       | medium_fast | 3.066 | 3.607 | 2.525 | 2.971 | 3.054 | 3.593 | 5.405 | 6.359 | 4.811 | 5.66  | ns |
|       | fast        | 3.046 | 3.584 | 2.513 | 2.957 | 3.034 | 3.57  | 5.401 | 6.353 | 4.803 | 5.651 | ns |
|       | slow        | 3.498 | 4.115 | 2.878 | 3.386 | 3.481 | 4.096 | 6.046 | 7.113 | 5.444 | 6.404 | ns |
| 12 mA | medium      | 3.138 | 3.692 | 2.569 | 3.023 | 3.126 | 3.678 | 5.782 | 6.803 | 5.129 | 6.034 | ns |
|       | medium_fast | 2.966 | 3.489 | 2.414 | 2.841 | 2.951 | 3.472 | 5.666 | 6.665 | 5.013 | 5.897 | ns |
|       | fast        | 2.945 | 3.464 | 2.401 | 2.826 | 2.93  | 3.448 | 5.659 | 6.658 | 5.003 | 5.886 | ns |
|       | slow        | 3.417 | 4.02  | 2.807 | 3.303 | 3.401 | 4.002 | 6.083 | 7.156 | 5.464 | 6.428 | ns |
| 16 mA | medium      | 3.076 | 3.618 | 2.519 | 2.964 | 3.063 | 3.604 | 5.828 | 6.856 | 5.176 | 6.089 | ns |
|       | medium_fast | 2.913 | 3.427 | 2.376 | 2.795 | 2.898 | 3.41  | 5.725 | 6.736 | 5.072 | 5.966 | ns |
|       | fast        | 2.894 | 3.405 | 2.362 | 2.78  | 2.879 | 3.388 | 5.715 | 6.724 | 5.064 | 5.957 | ns |
|       | slow        | 3.366 | 3.96  | 2.751 | 3.237 | 3.348 | 3.939 | 6.226 | 7.324 | 5.576 | 6.56  | ns |
|       | medium      | 3.03  | 3.565 | 2.47  | 2.906 | 3.017 | 3.55  | 5.981 | 7.036 | 5.282 | 6.214 | ns |
|       | medium_fast | 2.87  | 3.377 | 2.328 | 2.739 | 2.854 | 3.358 | 5.895 | 6.935 | 5.18  | 6.094 | ns |
|       | fast        | 2.853 | 3.357 | 2.314 | 2.723 | 2.837 | 3.338 | 5.889 | 6.929 | 5.177 | 6.09  | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management).

### 2.3.7 Differential I/O Standards

Configuration of the I/O modules as a differential pair is handled by Microsemi SoC Products Group Libero software when the user instantiates a differential I/O macro in the design. Differential I/Os can also be used in conjunction with the embedded Input register (InReg), Output register (OutReg), Enable register (EnReg), and Double Data Rate registers (DDR).

#### 2.3.7.1 LVDS

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard.

##### Minimum and Maximum Input and Output Levels

**Table 160 • LVDS Recommended DC Operating Conditions**

| Parameter      | Symbol    | Min   | Typ | Max   | Unit | Conditions  |
|----------------|-----------|-------|-----|-------|------|-------------|
| Supply voltage | $V_{DDI}$ | 2.375 | 2.5 | 2.625 | V    | 2.5 V range |
| Supply voltage | $V_{DDI}$ | 3.15  | 3.3 | 3.45  | V    | 3.3 V range |

**Table 161 • LVDS DC Input Voltage Specification**

| Parameter                       | Symbol        | Min | Max   | Unit | Conditions  |
|---------------------------------|---------------|-----|-------|------|-------------|
| DC Input voltage                | $V_I$         | 0   | 2.925 | V    | 2.5 V range |
| DC input voltage                | $V_I$         | 0   | 3.45  | V    | 3.3 V range |
| Input current high <sup>1</sup> | $I_{IH}$ (DC) |     |       |      |             |
| Input current low <sup>1</sup>  | $I_{IL}$ (DC) |     |       |      |             |

1. See Table 24, page 22.

**AC Switching Characteristics**

Worst commercial-case conditions:  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ ,  $V_{DDI} = 2.375\text{ V}$ .

**Table 210 • RSDS AC Switching Characteristics for Receiver (for MSIO I/O Bank - Input Buffers)**

| On-Die Termination (ODT) | $T_{PY}$ |       | Unit |
|--------------------------|----------|-------|------|
|                          | -1       | -Std  |      |
| None                     | 2.855    | 3.359 | ns   |
| 100                      | 2.85     | 3.353 | ns   |

**Table 211 • RSDS AC Switching Characteristics for Receiver (for MSIOD I/O Bank - Input Buffers)**

| On-Die Termination (ODT) | $T_{PY}$ |       | Unit |
|--------------------------|----------|-------|------|
|                          | -1       | -Std  |      |
| None                     | 2.602    | 3.061 | ns   |
| 100                      | 2.597    | 3.055 | ns   |

**Table 212 • RSDS AC Switching Characteristics for Transmitter (for MSIO I/O Bank - Output and Tristate Buffers)**

| $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}$ |       | $T_{LZ}$ |      | Unit |
|----------|-------|----------|-------|----------|-------|----------|-------|----------|------|------|
| -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std |      |
| 2.097    | 2.467 | 2.303    | 2.709 | 2.291    | 2.695 | 1.961    | 2.307 | 1.947    | 2.29 | ns   |

**Table 213 • RSDS AC Switching Characteristics for Transmitter (for MSIOD I/O Bank - Output and Tristate Buffers)**

|                  | $T_{DP}$ |       | $T_{ZL}$ |       | $T_{ZH}$ |       | $T_{HZ}$ |       | $T_{LZ}$ |       | Unit |
|------------------|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
|                  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  | -1       | -Std  |      |
| No pre-emphasis  | 1.614    | 1.899 | 1.559    | 1.834 | 1.55     | 1.823 | 1.59     | 1.87  | 1.575    | 1.852 | ns   |
| Min pre-emphasis | 1.604    | 1.887 | 1.742    | 2.05  | 1.728    | 2.032 | 1.889    | 2.222 | 1.858    | 2.185 | ns   |
| Med pre-emphasis | 1.521    | 1.79  | 1.753    | 2.062 | 1.737    | 2.043 | 1.9      | 2.235 | 1.868    | 2.197 | ns   |
| Max pre-emphasis | 1.492    | 1.754 | 1.762    | 2.073 | 1.745    | 2.052 | 1.91     | 2.247 | 1.876    | 2.206 | ns   |

**2.3.7.6 LVPECL**

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Similar to LVDS, two pins are needed. It also requires external resistor termination. IGLOO2 and SmartFusion2 SoC FPGAs support only LVPECL receivers and do not support LVPECL transmitters.

**Minimum and Maximum Input and Output Levels (Applicable to MSIO I/O Bank Only)**

**Table 214 • LVPECL Recommended DC Operating Conditions**

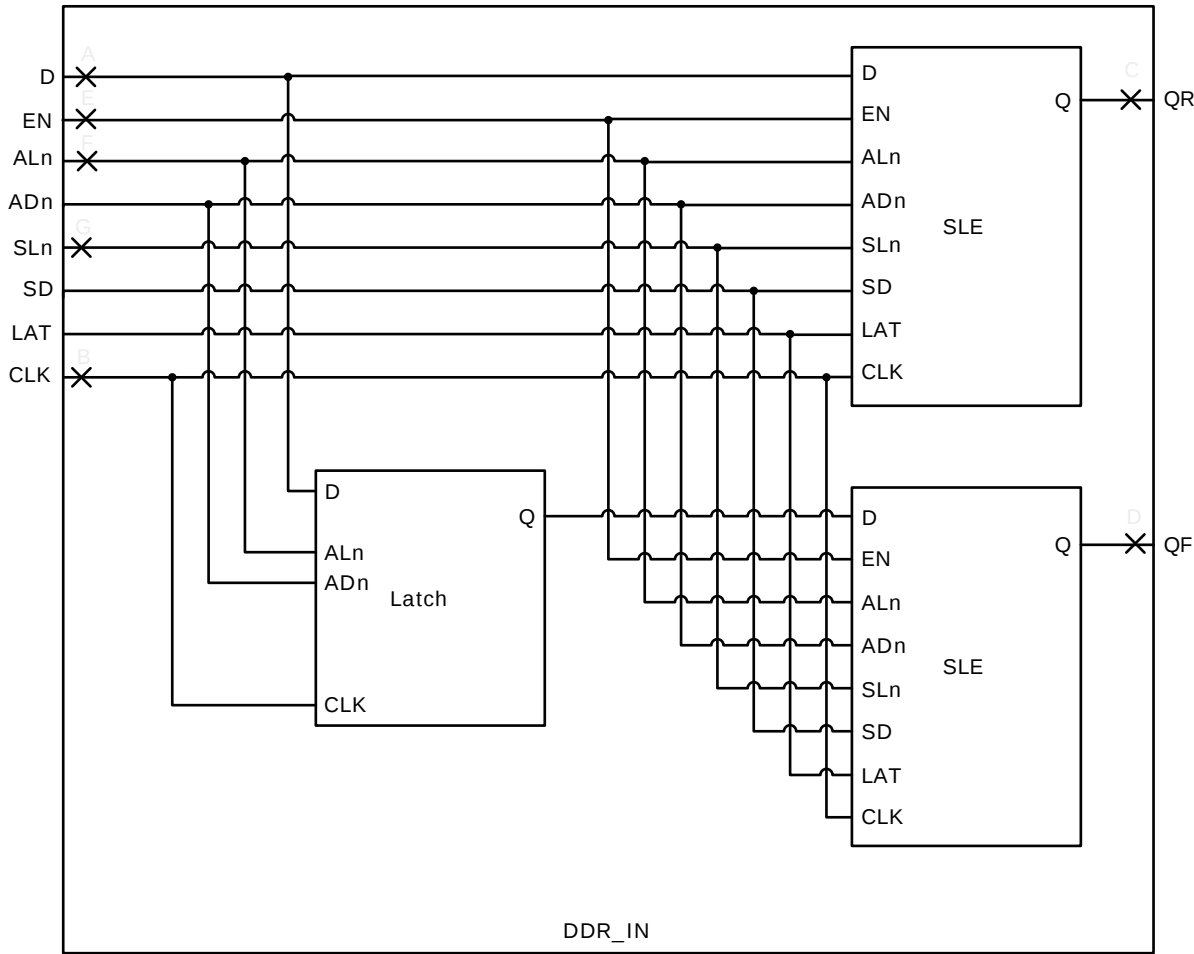
| Parameter      | Symbol    | Min  | Typ | Max  | Unit |
|----------------|-----------|------|-----|------|------|
| Supply voltage | $V_{DDI}$ | 3.15 | 3.3 | 3.45 | V    |

2.3.9 DDR Module Specification

This section describes input and output DDR module and timing specifications.

2.3.9.1 Input DDR Module

Figure 10 • Input DDR Module



The following table lists the RAM1K18 – two-port mode for depth × width configuration 512 × 36 in worst commercial-case conditions when  $T_J = 85\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 236 • RAM1K18 – Two-Port Mode for Depth × Width Configuration 512 × 36**

| Parameter                                                              | Symbol          | –1     |       | –Std   |       | Unit |
|------------------------------------------------------------------------|-----------------|--------|-------|--------|-------|------|
|                                                                        |                 | Min    | Max   | Min    | Max   |      |
| Clock period                                                           | $T_{CY}$        | 2.5    |       | 2.941  |       | ns   |
| Clock minimum pulse width high                                         | $T_{CLKMPWH}$   | 1.125  |       | 1.323  |       | ns   |
| Clock minimum pulse width low                                          | $T_{CLKMPWL}$   | 1.125  |       | 1.323  |       | ns   |
| Pipelined clock period                                                 | $T_{PLCY}$      | 2.5    |       | 2.941  |       | ns   |
| Pipelined clock minimum pulse width high                               | $T_{PLCLKMPWH}$ | 1.125  |       | 1.323  |       | ns   |
| Pipelined clock minimum pulse width low                                | $T_{PLCLKMPWL}$ | 1.125  |       | 1.323  |       | ns   |
| Read access time with pipeline register                                | $T_{CLK2Q}$     |        | 0.334 |        | 0.393 | ns   |
| Read access time without pipeline register                             |                 |        | 2.25  |        | 2.647 | ns   |
| Address setup time                                                     | $T_{ADDRSU}$    | 0.313  |       | 0.368  |       | ns   |
| Address hold time                                                      | $T_{ADDRHD}$    | 0.274  |       | 0.322  |       | ns   |
| Data setup time                                                        | $T_{DSU}$       | 0.337  |       | 0.396  |       | ns   |
| Data hold time                                                         | $T_{DHD}$       | 0.111  |       | 0.13   |       | ns   |
| Block select setup time                                                | $T_{BLKSU}$     | 0.207  |       | 0.244  |       | ns   |
| Block select hold time                                                 | $T_{BLKHD}$     | 0.201  |       | 0.237  |       | ns   |
| Block select to out disable time (when pipelined register is disabled) | $T_{BLK2Q}$     |        | 2.25  |        | 2.647 | ns   |
| Block select minimum pulse width                                       | $T_{BLKMPW}$    | 0.186  |       | 0.219  |       | ns   |
| Read enable setup time                                                 | $T_{RDESU}$     | 0.449  |       | 0.528  |       | ns   |
| Read enable hold time                                                  | $T_{RDEHD}$     | 0.167  |       | 0.197  |       | ns   |
| Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)                | $T_{RDPLESU}$   | 0.248  |       | 0.291  |       | ns   |
| Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)                 | $T_{RDPLEHD}$   | 0.102  |       | 0.12   |       | ns   |
| Asynchronous reset to output propagation delay                         | $T_{R2Q}$       |        | 1.506 |        | 1.772 | ns   |
| Asynchronous reset removal time                                        | $T_{RSTREM}$    | 0.506  |       | 0.595  |       | ns   |
| Asynchronous reset recovery time                                       | $T_{RSTREC}$    | 0.004  |       | 0.005  |       | ns   |
| Asynchronous reset minimum pulse width                                 | $T_{RSTMPW}$    | 0.301  |       | 0.354  |       | ns   |
| Pipelined register asynchronous reset removal time                     | $T_{PLRSTREM}$  | –0.279 |       | –0.328 |       | ns   |
| Pipelined register asynchronous reset recovery time                    | $T_{PLRSTREC}$  | 0.327  |       | 0.385  |       | ns   |
| Pipelined register asynchronous reset minimum pulse width              | $T_{PLRSTMPW}$  | 0.282  |       | 0.332  |       | ns   |
| Synchronous reset setup time                                           | $T_{SRSTSU}$    | 0.226  |       | 0.265  |       | ns   |
| Synchronous reset hold time                                            | $T_{SRSTHD}$    | 0.036  |       | 0.043  |       | ns   |
| Write enable setup time                                                | $T_{WESU}$      | 0.39   |       | 0.458  |       | ns   |
| Write enable hold time                                                 | $T_{WEHD}$      | 0.242  |       | 0.285  |       | ns   |
| Maximum frequency                                                      | $F_{MAX}$       |        | 400   |        | 340   | MHz  |

The following table lists the  $\mu$ SRAM in  $256 \times 4$  mode in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 241 •  $\mu$ SRAM (RAM256x4) in  $256 \times 4$  Mode**

| Parameter                                                                             | Symbol          | -1    |      | -Std  |      | Unit |
|---------------------------------------------------------------------------------------|-----------------|-------|------|-------|------|------|
|                                                                                       |                 | Min   | Max  | Min   | Max  |      |
| Read clock period                                                                     | $T_{CY}$        | 4     |      | 4     |      | ns   |
| Read clock minimum pulse width high                                                   | $T_{CLKMPWH}$   | 1.8   |      | 1.8   |      | ns   |
| Read clock minimum pulse width low                                                    | $T_{CLKMPWL}$   | 1.8   |      | 1.8   |      | ns   |
| Read pipeline clock period                                                            | $T_{PLCY}$      | 4     |      | 4     |      | ns   |
| Read pipeline clock minimum pulse width high                                          | $T_{PLCLKMPWH}$ | 1.8   |      | 1.8   |      | ns   |
| Read pipeline clock minimum pulse width low                                           | $T_{PLCLKMPWL}$ | 1.8   |      | 1.8   |      | ns   |
| Read access time with pipeline register                                               | $T_{CLK2Q}$     |       | 0.27 |       | 0.31 | ns   |
| Read access time without pipeline register                                            |                 |       | 1.75 |       | 2.06 | ns   |
| Read address setup time in synchronous mode                                           | $T_{ADDRSU}$    | 0.301 |      | 0.354 |      | ns   |
| Read address setup time in asynchronous mode                                          |                 | 1.931 |      | 2.272 |      | ns   |
| Read address hold time in synchronous mode                                            | $T_{ADDRHD}$    | 0.121 |      | 0.142 |      | ns   |
| Read address hold time in asynchronous mode                                           |                 | -0.65 |      | -0.76 |      | ns   |
| Read enable setup time                                                                | $T_{RDENSU}$    | 0.278 |      | 0.327 |      | ns   |
| Read enable hold time                                                                 | $T_{RDENHD}$    | 0.057 |      | 0.067 |      | ns   |
| Read block select setup time                                                          | $T_{BLKSU}$     | 1.839 |      | 2.163 |      | ns   |
| Read block select hold time                                                           | $T_{BLKHD}$     | -0.65 |      | -0.77 |      | ns   |
| Read block select to out disable time (when pipelined register is disabled)           | $T_{BLK2Q}$     |       | 2.09 |       | 2.46 | ns   |
| Read asynchronous reset removal time (pipelined clock)                                | $T_{RSTREM}$    | -0.02 |      | -0.03 |      | ns   |
| Read asynchronous reset removal time (non-pipelined clock)                            |                 | 0.046 |      | 0.054 |      | ns   |
| Read asynchronous reset recovery time (pipelined clock)                               | $T_{RSTREC}$    | 0.507 |      | 0.597 |      | ns   |
| Read asynchronous reset recovery time (non-pipelined clock)                           |                 | 0.236 |      | 0.278 |      | ns   |
| Read asynchronous reset to output propagation delay (with pipelined register enabled) | $T_{R2Q}$       |       | 0.83 |       | 0.98 | ns   |
| Read synchronous reset setup time                                                     | $T_{SRSTSU}$    | 0.271 |      | 0.319 |      | ns   |
| Read synchronous reset hold time                                                      | $T_{SRSTHD}$    | 0.061 |      | 0.071 |      | ns   |
| Write clock period                                                                    | $T_{CCY}$       | 4     |      | 4     |      | ns   |
| Write clock minimum pulse width high                                                  | $T_{CCLKMPWH}$  | 1.8   |      | 1.8   |      | ns   |
| Write clock minimum pulse width low                                                   | $T_{CCLKMPWL}$  | 1.8   |      | 1.8   |      | ns   |
| Write block setup time                                                                | $T_{BLKCSU}$    | 0.404 |      | 0.476 |      | ns   |
| Write block hold time                                                                 | $T_{BLKCHD}$    | 0.007 |      | 0.008 |      | ns   |
| Write input data setup time                                                           | $T_{DINCSU}$    | 0.101 |      | 0.118 |      | ns   |
| Write input data hold time                                                            | $T_{DINCHD}$    | 0.137 |      | 0.161 |      | ns   |
| Write address setup time                                                              | $T_{ADDRCSU}$   | 0.088 |      | 0.104 |      | ns   |

## 2.3.20 On-Chip Oscillator

The following tables describe the electrical characteristics of the available on-chip oscillators in the IGLOO2 FPGAs and SmartFusion2 SoC FPGAs.

**Table 280 • Electrical Characteristics of the 50 MHz RC Oscillator**

| Parameter                    | Symbol   | Typ   | Max       | Unit | Condition                      |
|------------------------------|----------|-------|-----------|------|--------------------------------|
| Operating frequency          | F50RC    | 50    |           | MHz  |                                |
| Accuracy                     | ACC50RC  | 1     | 4         | %    | 050 devices                    |
|                              |          | 1     | 5         | %    | 005, 025, and 060 devices      |
|                              |          | 1     | 6.3       | %    | 090 devices                    |
|                              |          | 1     | 7.1       | %    | 010 and 150 devices            |
| Output duty cycle            | CYC50RC  | 49–51 | 46.5–53.5 | %    |                                |
| Output jitter (peak to peak) | JIT50RC  |       |           |      | Period Jitter                  |
|                              |          | 200   | 300       | ps   | 005, 010, 050, and 060 devices |
|                              |          | 200   | 400       | ps   | 150 devices                    |
|                              |          | 300   | 500       | ps   | 025 and 090 devices            |
|                              |          |       |           |      | Cycle-to-Cycle Jitter          |
|                              |          | 200   | 300       | ps   | 005 and 050 devices            |
|                              |          | 320   | 420       | ps   | 010, 060, and 150 devices      |
|                              |          | 320   | 850       | ps   | 025 and 090 devices            |
| Operating current            | IDYN50RC | 6.5   |           | mA   |                                |

**Table 281 • Electrical Characteristics of the 1 MHz RC Oscillator**

| Parameter                    | Symbol  | Typ   | Max       | Unit | Condition                               |
|------------------------------|---------|-------|-----------|------|-----------------------------------------|
| Operating frequency          | F1RC    | 1     |           | MHz  |                                         |
| Accuracy                     | ACC1RC  | 1     | 3         | %    | 005, 010, 025, and 050 devices          |
|                              |         | 1     | 4.5       | %    | 060, and 150 devices                    |
|                              |         | 1     | 5.6       | %    | 090 devices                             |
| Output duty cycle            | CYC1RC  | 49–51 | 46.5–53.5 | %    | 005, 010, 025, 050, 090 and 150 devices |
|                              |         | 49–51 | 46.0–54.0 | %    | 060 devices                             |
| Output jitter (peak to peak) | JIT1RC  |       |           |      | Period Jitter                           |
|                              |         | 10    | 20        | ns   | 005, 010, 025, and 050 devices          |
|                              |         | 10    | 28        | ns   | 060, 090 and 150 devices                |
|                              |         |       |           |      | Cycle-to-Cycle Jitter                   |
|                              |         | 10    | 20        | ns   | 005, 010, and 050 devices               |
|                              |         | 10    | 35        | ns   | 025, 060, and 150 devices               |
|                              |         | 10    | 45        | ns   | 090 devices                             |
| Operating current            | IDYN1RC | 0.1   |           | mA   |                                         |
| Startup time                 | SU1RC   |       | 17        | μs   | 050, 090, and 150 devices               |
|                              |         |       | 18        | μs   | 005, 010, and 025 devices               |

### 2.3.30 SerDes Electrical and Timing AC and DC Characteristics

PCIe is a high-speed, packet-based, point-to-point, low-pin-count, serial interconnect bus. The IGLOO2 and SmartFusion2 SoC FPGAs has up to four hard high-speed serial interface blocks. Each SerDes block contains a PCIe system block. The PCIe system is connected to the SerDes block.

The following table lists the transmitter parameters in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 296 • Transmitter Parameters**

| Symbol        | Description                                                      | Min   | Max           | Unit          |
|---------------|------------------------------------------------------------------|-------|---------------|---------------|
| VTX-DIFF-PP   | Differential swing (2.5 Gbps, 5.0 Gbps)                          | 0.8   | 1.2           | V             |
| VTX-CM-AC-P   | Output common mode voltage (2.5 Gbps)                            |       | 20            | mV            |
| VTX-CM-AC-PP  | Output common mode voltage (5.0 Gbps)                            |       | 100           | mV            |
| VTX-RISE-FALL | Rise and fall time (20% to 80%, 2.5 Gbps)                        | 0.125 |               | UI            |
|               | Rise and fall time (20% to 80%, 5.0 Gbps)                        | 0.15  |               | UI            |
| ZTX-DIFF-DC   | Output impedance—differential                                    | 80    | 120           | $\Omega$      |
| LTX-SKEW      | Lane-to-lane TX skew within a SerDes block (2.5 Gbps)            |       | 500 ps + 2 UI | ps            |
|               | Lane-to-lane TX skew within a SerDes block (5.0 Gbps)            |       | 500 ps + 4 UI | ps            |
| RLTX-DIFF     | Return loss differential mode (2.5 Gbps)                         | –10   |               | dB            |
|               | Return loss differential mode (5.0 Gbps)<br>0.05 GHz to 1.25 GHz | –10   |               | dB            |
|               | 1.25 GHz to 2.5 GHz                                              | –8    |               | dB            |
| RLTX-CM       | Return loss common mode (2.5 Gbps, 5.0 Gbps)                     | –6    |               | dB            |
| TX-LOCK-RST   | Transmit PLL lock time from reset                                |       | 10            | $\mu\text{s}$ |
| VTX-AMP       | 100 mV setting                                                   | 90    | 150           | mV            |
|               | 400 mV setting                                                   | 320   | 480           | mV            |
|               | 800 mV setting                                                   | 660   | 940           | mV            |
|               | 1200 mV setting                                                  | 950   | 1400          | mV            |

### 2.3.31.3 Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given are for a 35 pF load on the pins and all sequential timing characteristics are related to SPI\_x\_CLK. For timing parameter definitions, see Figure 22, page 128.

The following table lists the SPI characteristics in worst-case industrial conditions when  $T_J = 100\text{ }^{\circ}\text{C}$ ,  $V_{DD} = 1.14\text{ V}$

**Table 305 • SPI Characteristics for All Devices**

| Symbol  | Description                                                                | Min   | Typ  | Max | Unit | Conditions                                                                                                        |
|---------|----------------------------------------------------------------------------|-------|------|-----|------|-------------------------------------------------------------------------------------------------------------------|
| SPIFMAX | Maximum operating frequency of SPI interface                               |       |      | 20  | MHz  |                                                                                                                   |
| sp1     | SPI_[0 1]_CLK minimum period                                               |       |      |     |      |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/2                                                     | 12    |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/4                                                     | 24.1  |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/8                                                     | 48.2  |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/16                                                    | 0.1   |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/32                                                    | 0.19  |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/64                                                    | 0.39  |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/128                                                   | 0.77  |      |     | μs   |                                                                                                                   |
| sp2     | SPI_[0 1]_CLK minimum pulse width high                                     |       |      |     |      |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/2                                                     | 6     |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/4                                                     | 12.05 |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/8                                                     | 24.1  |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/16                                                    | 0.05  |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/32                                                    | 0.095 |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/64                                                    | 0.195 |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/128                                                   | 0.385 |      |     | μs   |                                                                                                                   |
| sp3     | SPI_[0 1]_CLK minimum pulse width low                                      |       |      |     |      |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/2                                                     | 6     |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/4                                                     | 12.05 |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/8                                                     | 24.1  |      |     | ns   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/16                                                    | 0.05  |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/32                                                    | 0.095 |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/64                                                    | 0.195 |      |     | μs   |                                                                                                                   |
|         | SPI_[0 1]_CLK = PCLK/128                                                   | 0.385 |      |     | μs   |                                                                                                                   |
| sp4     | SPI_[0 1]_CLK, SPI_[0 1]_DO, SPI_[0 1]_SS rise time (10%–90%) <sup>1</sup> |       | 2.77 |     | ns   | I/O Configuration:<br>LVCMOS 2.5 V–<br>8 mA<br>AC loading: 35 pF<br>Test conditions:<br>Typical voltage,<br>25 °C |